# NSN 5961-00-431-7863

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### **Inclosure Material:**

Metal

### **Overall Length:**

Between 0.250 inches and 0.450 inches

### **Overall Diameter:**

0.875 inches

### **Mounting Facility Quantity:**

2

### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

### **Mounting Method:**

Unthreaded hole

### Features Provided:

Hermetically sealed case

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

50.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open

# Current Rating Per Characteristic:

Between 7.50 amperes source cutoff current and 30.00 amperes source cutoff current

### **Power Rating Per Characteristic:**

6.0 watts small-signal input power, common-collector preset

### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

### **Special Features:**

Junction pattern arrangement: npn

### Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

### **Specification Data:**

81349-mil-s-19500/413 government specification

### Shelf Life:

N/a

### Unit Of Measure:

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### Demilitarization:

No

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